

## Sketch of the solutions:

### Part A. Circuit dimensioning (2.4 points)

#### A.1

Using Ohm's law, the current through the voltage divisor is  $I = V_{\text{in}} / (R_x + R_y)$ , and  $V_{\text{out}} = R_y I$ . Thus

A.1

$$V_{\text{out}} = V_{\text{in}} \frac{R_y}{R_x + R_y}$$

0.2pt

#### A.2

A.2 Uncertainty in each measurement:  $\pm 0.01 \Omega$

0.5pt

#	$R_{T1}$	$R_{T2}$	$R_{T3}$
1	122.3	125.3	125.3
2	122.3	125.4	125.4
3	122.3	125.3	125.4
4	122.2	125.2	125.5
5	122.3	125.4	125.4
6	122.3	125.4	125.3
7	122.2	125.4	125.4
8	122.2	125.3	125.4
9	122.2	125.4	125.4
10	122.2	125.4	125.5
$\bar{R}$	122.25	125.35	125.40
$\sigma_R$	0.05	0.07	0.07

## A.3

- A.3** For a parallelepiped conductor of length  $l$ , width  $w$  and thickness  $t$ , the resistance is given by 0.3pt

$$R = \rho \frac{l}{wt}$$

For a thin film of square shape,  $l = w$ , thus

$$R = \rho \frac{l}{t \cancel{w}} = \frac{\rho}{t} = R_{\square}.$$

## A.4

The weighted average value (weighed by  $1/\sigma^2$ ) of the sheet resistance is  $\bar{R} = 123.94 \pm 0.04 \Omega$  and  $\rho = R_{\square} t$ .

- A.4**  $\bar{R} = 123.94 \pm 0.04 \Omega$   
 $\rho = 2.5 \pm 0.1 \times 10^{-3} \Omega \text{ m}.$  0.4pt

## A.5

- A.5** For a rectangular thin film  $R = R_{\square} \frac{l}{w}$ , thus 0.5pt

$$R_1 = R_2 = R_{\square} (1 + 1/0.9 + 1/0.8 + 1/0.7 + 1/0.6 + 1/0.5 + 1/0.4 + 1/0.3) = 14.2897 R_{\square}$$

Measured values:

$$R_1 = 1776 \pm 1 \Omega \quad k_1 = 14.33$$

$$R_2 = 1787 \pm 1 \Omega \quad k_2 = 14.42$$

$$\bar{k} = 14.3 \pm 0.1$$

Comparison with the theoretical value: the average value is compatible, within the assigned error bar, with the theoretical value.

## A.6

**A.6** Uncertainty in resistance measurements:  $\pm 1 \Omega$ .

0.3pt

Resistor  $R_1$ :

Points	$R_x/\Omega$	$R_y/\Omega$
Z	1776	0
A	1708	165
B	1578	296
C	1421	452
D	1239	607
E	1033	829
F	768	1072
G	439	1394
V	0	1782

Resistor  $R_2$ :

Points	$R_x/\Omega$	$R_y/\Omega$
Z	1791	0
H	1428	411
I	1120	737
J	882	996
K	670	1200
L	498	1396
M	341	1555
N	188	1719
W	0	1793

## A.7

A.7

0.3pt

Points	$V_{out}/V$	Points	$V_{out}/V$
Z	0	-	—
A	-0.208	H	0.664
B	-0.435	I	1.171
C	-0.699	J	1.593
D	-1.003	K	1.939
E	-1.337	L	2.24
F	-1.756	M	2.51
G	-2.29	N	2.77
V	-2.99	W	3.00

## Part B. Characteristic Curves of the JFET transistor (4.5 points)

### B.1

B.1  $I_{DS} = 11.84 \pm 0.01$  mA

0.2pt

## B.2

B.2	$I_{DS}$ currents in mA:									0.8pt
Gate/Drain	Z	H	I	J	K	L	M	N	W	
Z	0	1.58	2.18	2.82	3.60	4.75	6.45	9.43	11.87	
A	0	1.52	2.13	2.67	3.47	4.53	6.04	7.82	8.78	
B	0	1.45	2.00	2.63	3.29	4.21	5.15	5.77	6.09	
C	0	1.28	1.79	2.23	2.59	2.85	2.99	3.08	3.16	
D	0	0.65	0.76	0.81	0.85	0.89	0.92	0.94	0.96	
E	0	0.03	0.04	0.05	0.05	0.05	0.05	0.06	0.07	
F	0	0	0	0	0	0	0	0	0	
G	0	0	0	0	0	0	0	0	0	
V	0	0	0	0	0	0	0	0	0	

## B.3

The unloaded voltage is

$$V_{\text{out}} = V_{\text{in}} \frac{R_y}{R_x + R_y}$$

and the loaded voltage is

$$V_{\text{out}}^L = V_{\text{in}} \frac{R'_y}{R_x + R'_y},$$

where  $R'_y$  is the equivalent resistance of the parallel association between  $R_y$  and  $R_L$ :

$$R'_y = \frac{R_y R_L}{R_y + R_L}.$$

Thus,

$$f = \frac{\frac{R'_y}{R_x + R'_y}}{\frac{R_y}{R_x + R_y}} = \frac{(R_x + R_y)R'_y}{(R_x + R'_y)R_y} = \frac{(R_x + R_y) \frac{R_L}{R_y + R_L}}{R_x + R_y \frac{R_L}{R_y + R_L}}$$

Note that in terms of  $\eta = 1/(1 + \frac{R_y}{R_L})$ , the factor  $f$  can be written as

$$f = \frac{(R_x + R_y)\eta}{R_x + R_y\eta}$$

When  $R_L \gg R_y$ ,  $\eta \rightarrow 1$ , and  $f \rightarrow 1$ ; when  $R_L \ll R_y$ ,  $\eta \rightarrow 0$  and  $f \rightarrow 0$ .

**B.3**

$$f = \frac{(R_x + R_y)\eta}{R_x + R_y\eta}$$

0.2pt

**B.4**

**B.4**

Gate: A     $V_{GS} = 0 \text{ V}$      $R_{DS} = 50.0$

0.7pt

Drain	$V_{out}/\text{V}$	$V_{out}^L/\text{V}$	$V_{DS}/\text{V}$	$I_{DS}/\text{mA}$	$rI/\text{V}$	$f$
Z	0,000	0,000	0,000	0,00	0,000	1,000
H	0,664	0,105	0,089	1,58	0,016	0,158
I	1,171	0,139	0,117	2,18	0,022	0,119
J	1,593	0,181	0,153	2,82	0,028	0,114
K	1,939	0,237	0,201	3,60	0,036	0,122
L	2,240	0,315	0,267	4,75	0,048	0,140
M	2,510	0,443	0,379	6,45	0,065	0,177
N	2,770	0,724	0,630	9,43	0,094	0,261
W	3,000	3,000	2,881	11,87	0,119	1,000

**B.4**

0.7pt

cont.

Gate: B  $V_{GS} = -0.208 \text{ V}$   $R_{DS} = 58.73$

Drain	$V_{out}/\text{V}$	$V_{out}^L/\text{V}$	$V_{DS}/\text{V}$	$I_{DS}/\text{mA}$	$rI/\text{V}$	$f$
Z	0.000	0.000	0.000	0.00	0.000	1.000
H	0.664	0.118	0.102	1.52	0.015	0.177
I	1.171	0.157	0.136	2.13	0.021	0.134
J	1.593	0.204	0.177	2.67	0.027	0.128
K	1.939	0.267	0.233	3.47	0.035	0.138
L	2.240	0.353	0.308	4.53	0.045	0.158
M	2.510	0.495	0.435	6.04	0.060	0.197
N	2.770	0.799	0.721	7.82	0.078	0.289
W	3.000	3.000	2.912	8.78	0.088	1.000

Gate: C  $V_{GS} = -0.435 \text{ V}$   $R_{DS} = 72.54$

Drain	$V_{out}/\text{V}$	$V_{out}^L/\text{V}$	$V_{DS}/\text{V}$	$I_{DS}/\text{mA}$	$rI/\text{V}$	$f$
Z	0.000	0.000	0.000	0.00	0.000	1.000
H	0.664	0.136	0.122	1.45	0.015	0.205
I	1.171	0.183	0.163	2.00	0.020	0.157
J	1.593	0.239	0.213	2.63	0.026	0.150
K	1.939	0.312	0.279	3.29	0.033	0.161
L	2.240	0.411	0.369	4.21	0.042	0.184
M	2.510	0.572	0.520	5.15	0.052	0.228
N	2.770	0.907	0.850	5.77	0.058	0.328
W	3.000	3.000	2.939	6.09	0.061	1.000

**B.4**

0.7pt

cont.

Gate: D  $V_{GS} = -0.699\text{ V}$   $R_{DS} = 99.86$

Drain	$V_{out}/\text{V}$	$V_{out}^L/\text{V}$	$V_{DS}/\text{V}$	$I_{DS}/\text{mA}$	$rI/\text{V}$	$f$
Z	0.000	0.000	0.000	0.00	0.000	1.000
H	0.664	0.170	0.157	1.28	0.013	0.256
I	1.171	0.232	0.214	1.79	0.018	0.198
J	1.593	0.303	0.281	2.23	0.022	0.190
K	1.939	0.395	0.369	2.59	0.026	0.204
L	2.240	0.516	0.487	2.85	0.029	0.230
M	2.510	0.708	0.678	2.99	0.030	0.282
N	2.770	1.089	1.059	3.08	0.031	0.393
W	3.000	3.000	2.968	3.16	0.032	1.000

Gate: E  $V_{GS} = -1.003\text{ V}$   $R_{DS} = 176.3$

Drain	$V_{out}/\text{V}$	$V_{out}^L/\text{V}$	$V_{DS}/\text{V}$	$I_{DS}/\text{mA}$	$rI/\text{V}$	$f$
Z	0.000	0.000	0.000	0.00	0.000	1.000
H	0.664	0.245	0.238	0.65	0.007	0.369
I	1.171	0.346	0.338	0.76	0.008	0.295
J	1.593	0.454	0.446	0.81	0.008	0.285
K	1.939	0.586	0.578	0.85	0.009	0.302
L	2.240	0.754	0.745	0.89	0.009	0.337
M	2.510	1.004	0.994	0.92	0.009	0.400
N	2.770	1.451	1.441	0.94	0.009	0.524
W	3.000	3.000	2.990	0.96	0.010	1.000



**B.4**  
cont.

1.2pt

Gate: F  $V_{GS} = -1.337 \text{ V}$   $R_{DS} = 1111$

Drain	$V_{out}/\text{V}$	$V_{out}^L/\text{V}$	$V_{DS}/\text{V}$	$I_{DS}/\text{mA}$	$rI/\text{V}$	$f$
Z	0.000	0.000	0.000	0.00	0.000	1.000
H	0.664	0.526	0.523	0.03	0.003	0.791
I	1.171	0.857	0.853	0.04	0.004	0.732
J	1.593	1.149	1.144	0.05	0.005	0.721
K	1.939	1.431	1.426	0.05	0.005	0.738
L	2.240	1.719	1.714	0.05	0.005	0.767
M	2.510	2.039	2.034	0.05	0.005	0.812
N	2.770	2.430	2.424	0.06	0.006	0.877
W	3.000	3.000	2.993	0.07	0.007	1.000

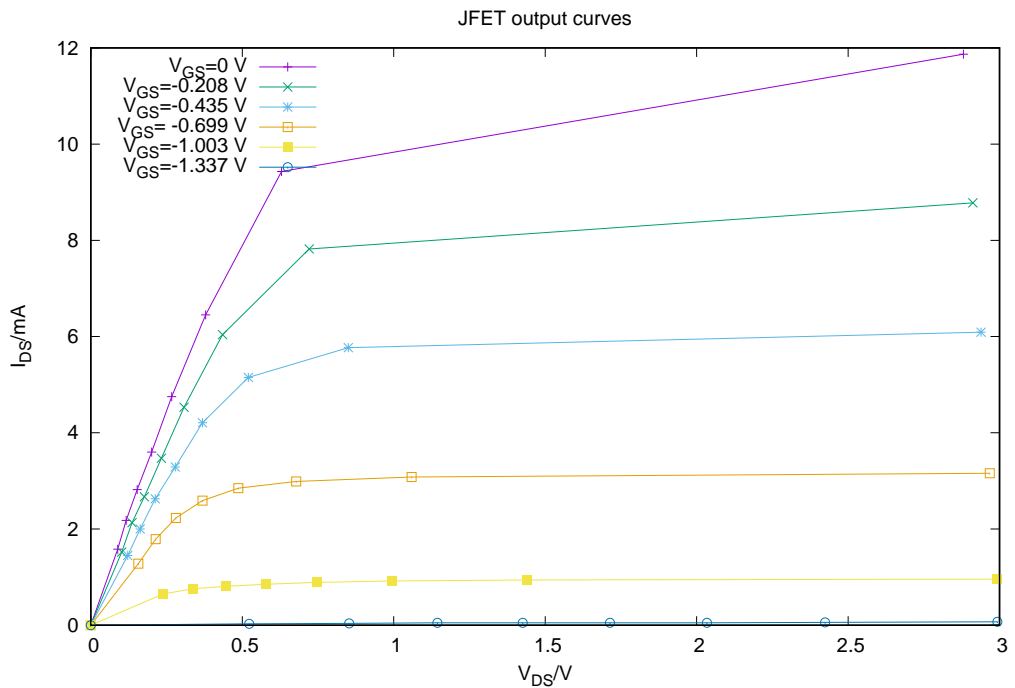
Gate: G  $V_{GS} = -1.756 \text{ V}$   $R_{DS} = \infty$

Drain	$V_{out}/\text{V}$	$V_{out}^L/\text{V}$	$V_{DS}/\text{V}$	$I_{DS}/\text{mA}$	$rI/\text{V}$	$f$
Z	0.000	0.000	0.000	0.00	0.000	1.000
H	0.664	-0.288	-0.288	0.00	0.000	-0.434
I	1.171	-0.325	-0.325	0.00	0.000	-0.278
J	1.593	-0.415	-0.415	0.00	0.000	-0.260
K	1.939	-0.562	-0.562	0.00	0.000	-0.290
L	2.240	-0.800	-0.800	0.00	0.000	-0.357
M	2.510	-1.325	-1.325	0.00	0.000	-0.528
N	2.770	-3.675	-3.675	0.00	0.000	-1.327
W	3.000	3.000	3.000	0.00	0.000	1.000

## B.5

B.5 Output curves:

0.5pt



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## B.6

The  $R_{DS}$  values are obtained from the slopes of the linear region of the output curves (small  $V_{DS}$  voltages).

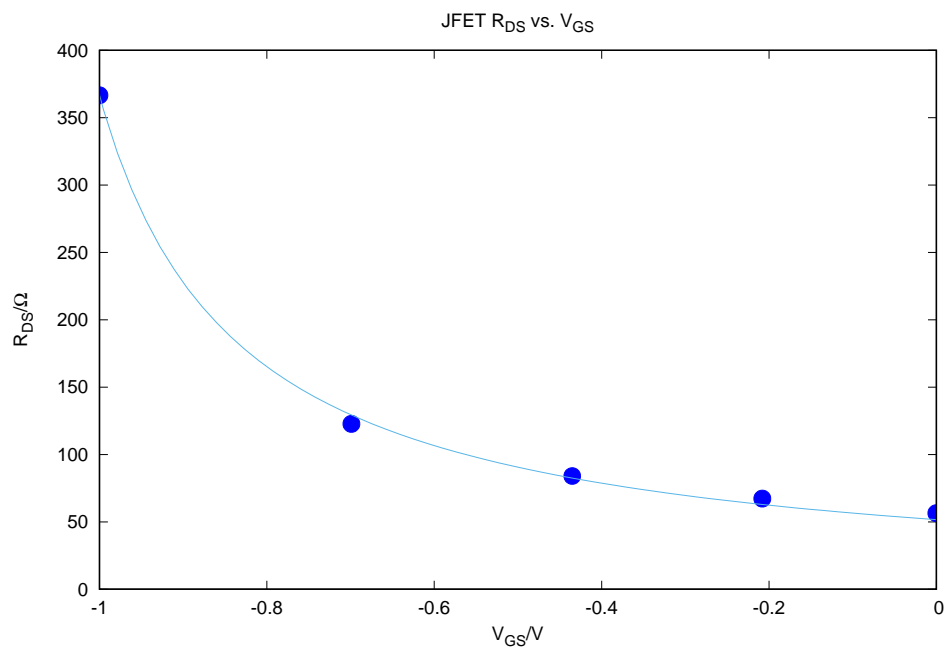
The last point in the plot  $R_{DS}(V_{GS})$  has a large error bars as we are missing points in the linear regime, and will be ignored.

The solid line in the plot is the result of a fit to  $R_{DS} = R_{DS}^0 (1 - V_{GS}/V_P)$ , that gave  $R_{DS}^0 = 52(2)\ \Omega$ ,  $V_P = -1.18(1)\text{ V}$ .

B.6

0.5pt

$V_{GS}/V$	$R_{DS}/\Omega$
0	$56.5 \pm 2$
-0.208	$67.4 \pm 2$
-0.435	$84.1 \pm 4$
-0.699	$122.84 \pm 4$
-1.003	$366.6 \pm 4$
-1.337	$1111 \pm 100$



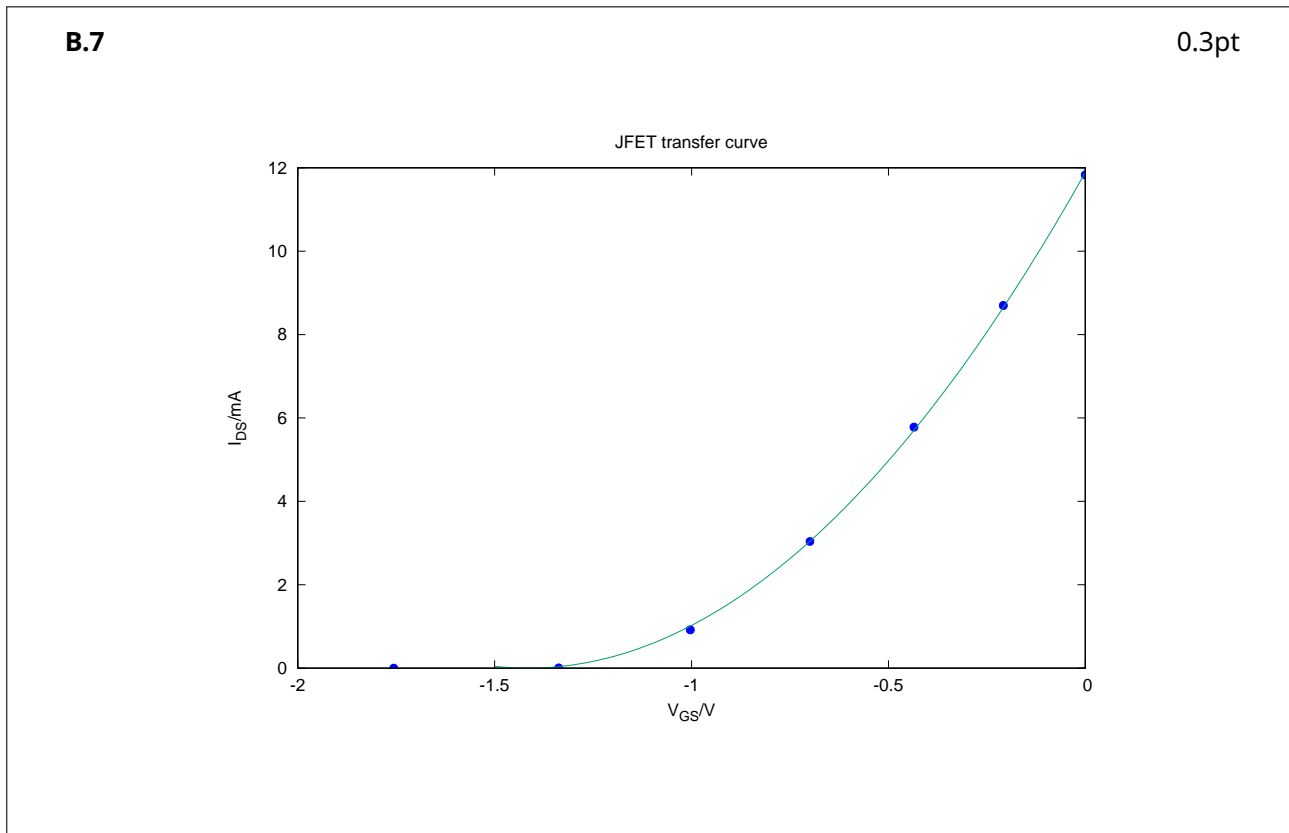
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## B.7

The data was obtained with  $V_{DS} = +3$  V. The solid line is the result of the fit to the data of the function

$$I_{DS} = I_{DSS} (1 - V_{GS}/V_P)^2.$$

The fitted parameters are  $I_{DSS} = 11.89 \pm 0.06$  mA and  $V_P = -1.42 \pm 0.02$  V.



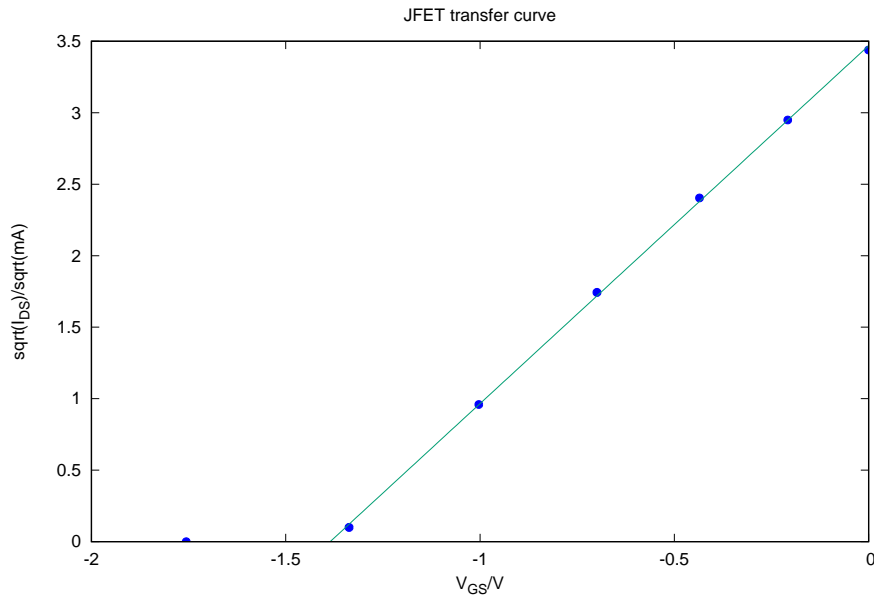
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## B.8

From

$$I_{DS} = I_{DSS} (1 - V_{GS}/V_P)^2$$

a plot of  $\sqrt{I_{DS}}$  as function of  $V_{GS}$  should yield a straight line with slope  $a = -\sqrt{I_{DS}}/V_P$  that intercepts the  $x$ -axis at  $V_P$ .



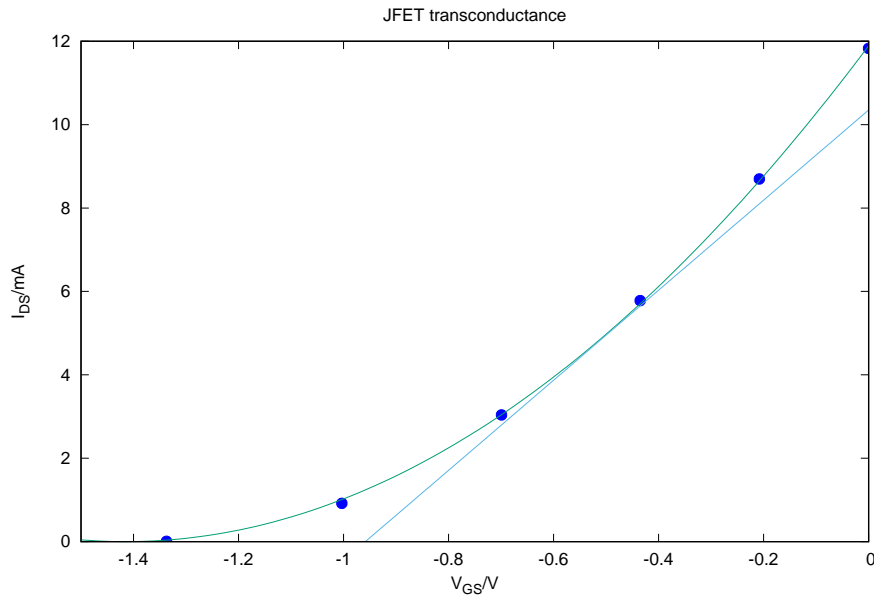
A linear fit to  $f(x) = ax + b$  gave  $a = 2.50(2)$  and  $b = 3.47(2)$ . Thus,  $V_p = -b/a = -1.39(2)$  V and  $I_{DSS} = 4.23^2 = 12.0(2)$  mA.

**B.8**  $V_p = -b/a = -1.39(2)$  V  
 $I_{DSS} = 4.23^2 = 12.0(2)$  mA.

0.4pt

## B.9

The transconductance is the slope of the transfer curve at a given point. From the transfer plot, we draw the tangent at the point with abscissa  $-0.50$  V and read the slope from the graph, obtaining  $g = 10.8(1)$  m<sup>-1</sup>.



From

$$I_D = I_{DSS} (1 - V_{GS}/V_P)^2,$$

$$g = \frac{\partial I_{DS}}{\partial V_{GS}} = 2I_{DSS} (1 - V_{GS}/V_P) \left( -\frac{1}{V_P} \right) = \frac{2I_{DSS}}{V_P} (V_{GS}/V_P - 1).$$

Substituting values,

$$g = 10.8 \text{ m}^{-1}$$

a value that agrees with that obtained using the graphical method.

**B.9**  $g_{\text{measured}} = 10.8(1) \text{ m}^{-1}$   
 $g_{\text{model}} = 10.8 \text{ m}^{-1}$

0.4pt

**Part C: The Paper Thin Film Transistor (2.0 points)**

**C.1**

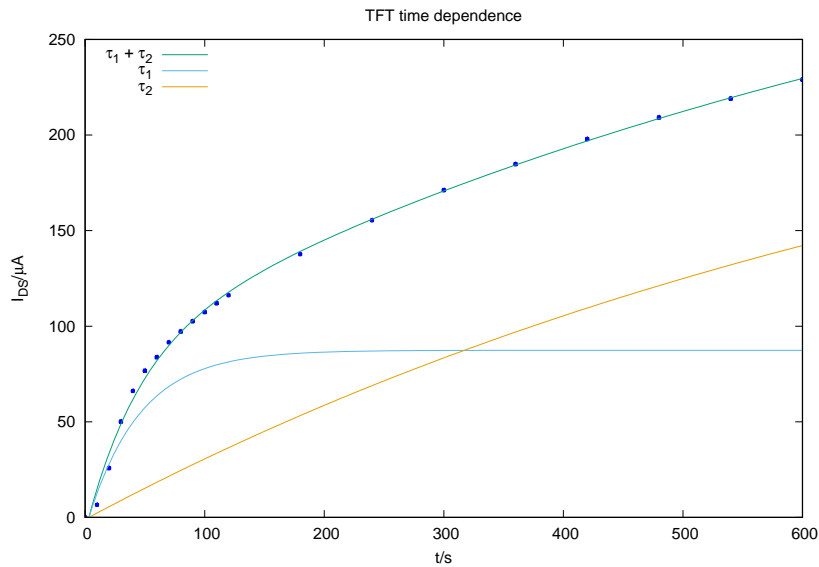
<b>C.1</b>					0.8pt
	$t/s$	$I_{DS}/\mu A$	$t/s$	$I_{DS}/\mu A$	
	0	0	110	112,0	
	10	6.6	120	116.2	
	20	25.8	180	137.7	
	30	50.1	240	155.4	
	40	66.2	300	171.2	
	50	76.7	360	184.4	
	60	83.8	420	197.9	
	70	91.6	480	209.2	
	80	97.2	540	219.1	
	90	102.6	600	220.0	
	100	107.4	-	-	

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**C.2**

The data is similar to that of the charge of a capacitor, superimposed with an almost linear component that corresponds to the charge of the second capacitor with a larger time constant.

A least squares fit to a  $A(1 - \exp(-t/\tau_1)) + B(1 - \exp(-t/\tau_2))$  is also depicted, showing that the data can be well fitted by this model. The shorter time constant is  $\tau_1 = 43(8)$  s, the longer time constant,  $\tau_2$  is roughly 20 times larger.



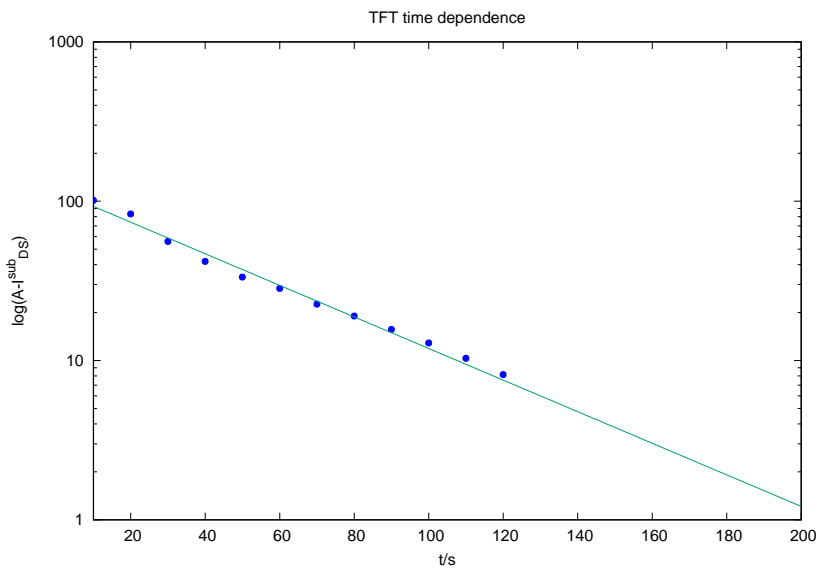
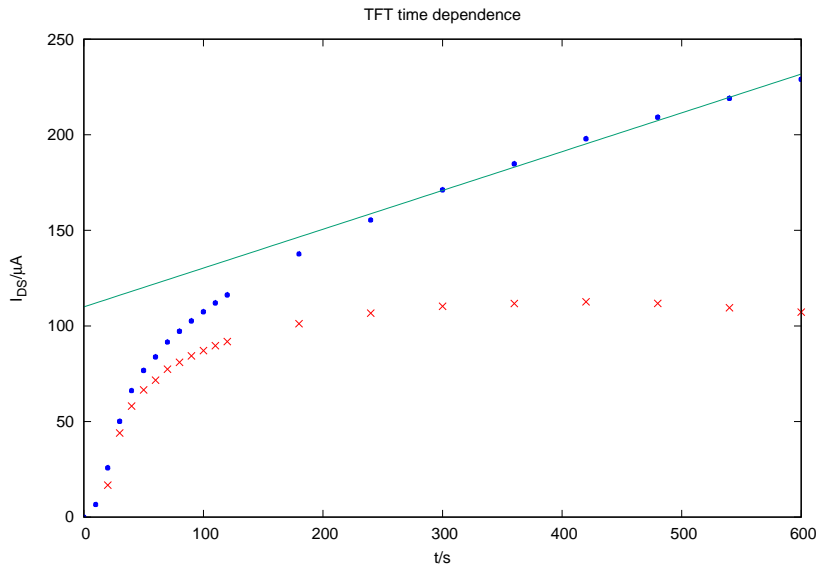
Let  $I_{DS}^{\text{sub}} = A(1 - \exp(-t/\tau_1))$  be the data subtracted from the long time constant component. A logarithmic plot of  $\log(A - I_{DS}^{\text{sub}})$  should be a straight line of slope  $-1/\tau_1$ . The constant  $A$ , the saturation current of the short  $\tau_1$  component, can be easily estimated from the above plot.

The slope of the line is  $m = -0.023(1)$ , from which we get  $\tau_1 = 44(3)$  s. The error bar is underestimated, as it does not take into account the error in the subtraction of the  $\tau_2$  component.



C.2

1.2pt



$$\tau_1 = 44(3) \text{ s.}$$

## Part D. Inverter Circuit (1.0 points)

### D.1

D.1  $R_L = 198 \text{ k}\Omega$

0.5pt

$t$	$V_{in}/V$	$V_{out}/V$
	-2.983	2.456
	-2.760	2.470
	-2.567	2.461
	-2.340	2.461
	-2.058	2.460
	-1.719	2.252
	-1.330	0.889
	-0.775	0.039

### D.2

D.2

0.5pt

